Importance of constructing synergistic protective layers in Si-reduced graphene oxide-amorphous carbon ternary composite as anode for lithium-ion batteries

Yang Yang, Guiyan Sun, Jiali Lin, Dingqiong Chen, Yiyong Zhang, Jinbao Zhao*

State Key Laboratory of Physical Chemistry of Solid Surfaces, College of Chemistry and Chemical Engineering, Collaborative Innovation Center of Chemistry for Energy Materials, Xiamen University, Xiamen 361005, China

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A B S T R A C T

Si is regarded as a promising anode candidate for lithium-ion batteries (LIBs) due to its high theoretical capacity and appropriate Li$^+$ ions insertion voltage (<0.4 V vs Li$^+$/Li). However, its intrinsic inferior electronic conductivity and huge volume changes during cycling lead to poor cyclic performance. Integrating Si with carbon materials has been proved to be an efficient route to improve its electrochemical performance. In this report, we successfully synthesized Si-reduced graphene oxide-amorphous carbon (Si-rGO-C) composite assisted with a facile guar gum hydrogel method and studied the protective effect of different kinds of carbon. In the Si-rGO-C ternary composite, the Si nanoparticles (NPs) are embedded in amorphous carbon and tightly anchored to rGO sheets. The amorphous carbon and rGO serve as synergistic protective layers. The Si-rGO-C composite possesses good structural integrity accompanied by enhanced conductive framework. The resulting Si-rGO-C composite exhibits much improved electrochemical performance (a high capacity of 913 mAh g$^{-1}$ can be maintained after 100 cycles at 0.5 A g$^{-1}$ with almost no capacity decay) compared with the Si-rGO and Si-C composites with only single protective layer, indicating the importance of constructing synergistic carbon layers in Si-rGO-C ternary composite for LIB anodes.

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1. Introduction

Since the successful commercial launch of lithium ion batteries (LIBs) by Sony Corporation 26 years ago (1991), LIBs have been extensively utilized for the present-day portable electronic devices [1,2]. However, there is a crucial demand to develop LIBs with higher energy density with the growing need for electric vehicle and energy storage system [3,4]. Anode is an indispensable component of LIB, increasing the specific capacity of anodes is an effective approach to increase the energy density of LIB. Nowadays the widely used LIB anode is still graphite, but its theoretical capacity is only 372 mAh g$^{-1}$ [5,6]. Thus developing anode materials having much higher capacity to replace graphite is a direct approach to boost the LIB energy density [7].

Si is considered to be one of the most promising anode candidates on account of its high theoretical specific capacity (4200 mAh g$^{-1}$) and appropriate Li$^+$ ions insertion potential (<0.4 V vs Li$^+$/Li) [8–10]. However, Si is easy to pulverize due to huge volume changes (~300%) during repeating Li insertion and extraction processes, combined with its intrinsically low electronic conductivity, the capacity of Si anodes decays quickly [11,12].

Many efforts have been made to overcome these challenging obstacles. One effective way is to fabricate nanostructured or nanoscale Si anodes such as Si nanoparticle [13,14], Si nanowire [15–17], Si nanotube [18,19], Si thin film [20,21] and hollow Si [22–24]. These nanoscale morphologies are designed to provide facile strain relaxation to minimize electrode pulverization and shorten the diffusion paths of Li$^+$ ions [25,26]. Another feasible route is to integrate Si with an electronically conducting carbon matrix [27–32]. Recently, graphene has been extensively studied to construct the conducting networks between Si because of its good mechanical flexibility and high electronic conductivity [31,33–35]. The graphene sheets can not only enhance the electronic conductivity but also work as a protective layer to relieve the strain during cycling [36]. How to make Si particles tightly anchored to the graphene sheets is the key point. Zhong et al. [32] fabricated sandwich-like graphene-Si hybrid films
by hydrothermal process and electrostatic adsorption. Lin et al. [33] synthesized Si@carbon/rGO composite assisted by polyamiline. Chang et al. [34] prepared carbon-coated Si/rGO nanostructure anchored by nickel foam with carbon nanotubes by chemical vapor deposition (CVD) method. Lin et al. [35] prepared yolk-shell Si-rGO/ amorphous carbon material by means of electrostatic self-assembly and hydrothermal process. All of these studies indicated that constructing dual-carbon layers (amorphous carbon and graphene) to fabricate Si-rGO-C ternary composite can greatly improve cycle performance of Si-based anodes. However, these synthetic processes usually involve hydrothermal method, CVD or HF etching, which is costly and complex. It is still a challenge to develop a simple and scalable route to fabricate Si-rGO-C ternary composite with superior electrochemical performance.

Herein, we report a facile and effective strategy for synthesis of Si-rGO-C ternary composite. All of the raw materials are commercially available and without treatment, and the process is simple and scalable. First, the Si NPs, GO and guar gum are added into water, after stirring a hydrogel is formed (Fig. 1). Then, the hydrogel is freeze-dried and annealed in inert gas to obtain the final Si-rGO-C composite. The guar gum not only helps to form hydrogel in which Si and GO are glued together but also serves as carbon source which can be carbonized to amorphous carbon after pyrolysis. In this specific structure, the Si NPs coated with amorphous carbon are well wrapped by rGO to maintain the good structural integrity and conductive contact. In order to study the importance of constructing these synergistic protective layers (amorphous carbon and graphene), the Si-C (without GO added) and Si-rGO (without guar gum) samples are also prepared according to the same method. The Si-rGO-C composite exhibits the best electrochemical performance compared to Si-C and Si-G samples.

2. Experiment

2.1. Chemicals and materials

The Si NPs powder (crystalline, APS ≤ 50 nm, 98%, Alfa aesar), GO aqueous suspension (wt% = 2%, Shanghai Ashine Technology Development Co., Ltd), and guar gum (Henan Honest Food Co., Ltd) were used as received without further purification.

2.2. Synthesis of Si-rGO-C ternary composite

In a typical synthesis, 2 g GO aqueous suspension was added into 8 mL of deionized water and dispersed by ultrasonication for 1 h. 0.1 g Si NPs powder were added into 10 mL deionized water and dispersed by ultrasonication for 1 h. The Si NPs aqueous dispersion was mixed with the as-obtained GO aqueous dispersion, 0.3 g guar gum was added and stirred vigorously for 3 h. The resulting hydrogel was freeze-dried and annealed at 700 °C for 3 h under a H2/Ar (v/v = 10:90) atmosphere with the heat rate of 5 °C min⁻¹ to obtain the final Si-rGO-C ternary composite. The Si-rGO and Si-C composites were prepared by the same procedure without the addition of guar gum and GO, respectively.

2.3. Characterization

X-ray diffraction (XRD) patterns were collected with a Rigaku miniflex 600 instrument using Cu Kα radiation (λ = 0.154 nm). Raman spectrum were measured using the inVia Raman microscope (Renishaw) equipped with a 532 nm Ar-ion laser. Material morphology was visualized by using a field-emission scanning electron microscopy (FE-SEM, Hitachi S4800). TEM images were obtained on the high-resolution transmission electron microscopy (HR-TEM, FEI, TECNAI G2 F30) and (JEOL-2100). Thermogravimetric analysis (TGA) was conducted on the SDT Q600 (TA Instruments) under air flow (20–800 °C with the heat rate of 10 °C min⁻¹). Powder electronic conductivity measurements were conducted on the Power Resistivity Meter SZT-D (Suzhou Jingge Electronics Co., Ltd.).

2.4. Electrochemical measurements

The working electrode was fabricated by mixing 60 wt% composite, 20% acetylene black, 10% vapor grown carbon fiber (VGCF), and 10% bi-component binders of same weight ratio of carboxyl methyl cellulose (CMC) and styrene-butadiene resin (SBR) in deionized water into a homogenous slurry. The slurry was coated onto a Cu foil and then dried in a vacuum oven at 80 °C for 12 h. The loading weight was 1.1–1.4 mg cm⁻². All specific capacities in the manuscript were calculated based on the total mass of the active material (including Si, amorphous carbon, and reduced graphene oxide). The 2016-type coin cells were assembled by using lithium metal as the counter electrode and celgard 2400 as the separator. The electrolyte was LiPF6 (1 M) in the mixture of ethylene carbonate (EC)/diethyl carbonate (DEC) (v/v = 1:1) containing 10 wt% fluoroethylene carbonate (FEC) as the additive. The charge-discharge experiments were carried out on a battery cycler (Neware BTS battery charger, Shenzhen, China) at various current rates. Electrochemical impedance spectroscopy (EIS) measurements were performed on the Autolab 302N with the frequency range from 0.1 Hz to 100 kHz. Cyclic voltammetry (CV) tests were carried out on the CHI 1030C electrochemical workstation at the scan rate of 0.1 mV s⁻¹. All of the electrochemical properties were measured at 25 °C.

3. Results and discussion

The X-ray diffraction (XRD) patterns of pristine Si, Si-rGO, Si-C and Si-rGO-C samples are shown in Fig. 2. Diffraction peaks of the
synthesized Si-rGO, Si-C and Si-rGO-C composites match well with pristine Si and agree with the (111), (220), (311), (400), (331), and (422) diffraction planes of cubic structure Si (JCPDF card No. 27-1402).

For the Raman spectra of all four samples (Fig. 3a), a strong peak located at 521 cm\(^{-1}\) and a small peak at 954 cm\(^{-1}\) should correspond to the characteristic Raman shift of crystalline Si \([37-39]\). The broad peaks at 1346 and 1600 cm\(^{-1}\) in Si-rGO, Si-C and Si-rGO-C composites correspond to D and G bands of the carbon (amorphous carbon and rGO), which are linked to disordered carbon and relative motion of sp\(^2\)-bonded graphitic carbon atoms, respectively \([40-42]\). The results indicate that carbon materials have been successfully introduced into the composites. The TG curves of these samples are shown in Fig. 3b. All samples are heated to 800 °C in air so that Si is partly oxidized to SiO\(_x\) and carbon is combusted to CO\(_2\) \([43,44]\). The weight loss of three composites between 400 and 600 °C should be attributed to these two processes together. The residual weight of pristine Si is about 102.49%, thus the carbon contents of Si-rGO, Si-C and Si-rGO-C composites are determined to be 18.02%, 35.80% and 41.64%, respectively.

The SEM images of Si-rGO, Si-C and Si-rGO-C composites are presented in Fig. 4. The three composites show distinctly different

![Fig. 3. Raman spectra and TG curves of pristine Si, Si-rGO, Si-C and Si-rGO-C samples.](image)

![Fig. 4. SEM images of (a, b) Si-rGO composite, (c, d) Si-C composite and (e, f) Si-rGO-C composite.](image)
morphologies. We can see wrinkled rGO sheets in the Si-rGO composite (Fig. 4a and b). However, the contact between Si NPs and rGO is very loose without guar gum serving as the “glue”. For the Si-C composite (Fig. 4c and d), Si NPs are encapsulated by amorphous carbon and interconnected to micro scale clusters due to the carbonization of guar gum hydrogel. The Si-rGO-C composite (Fig. 4e) looks like a pile of books scattered on the floor. In every “book”, Si NPs are interconnected to clusters by amorphous carbon like Si-C composite and well wrapped by rGO sheets (Fig. 4f).

The TEM images of these composites are shown in Fig. 5. After ultrasonic treatment which is used to disperse samples prior to TEM characterization, there is only a little amount of Si NPs still anchored on the rGO sheets for the Si-rGO composite (Fig. 5a). However, the bonding between Si NPs and rGO in the Si-rGO-C composite is very strong (Fig. 5e). In Fig. 5b, an amorphous layer (SiOx) of about 2 nm in thickness can be observed on the surface of a single Si NP. The lattice fringes inside are calibrated to have a lattice spacing of d = 0.31 nm, corresponding to the (111) plane of crystalline Si. Fig. 5d reveals that the amorphous carbon layer (about 7 nm in thickness) has been coated onto Si NPs in the Si-C composite. Fig. 7e and f reveal that Si NPs are interconnected and tightly anchored to the rGO in the Si-rGO-C composite. Double coating layers made of amorphous carbon and rGO (wrinkles in Fig. 5g and h) can be clearly observed on the surface of Si NPs. The EDX mapping was also conducted on the Si-rGO-C composite (Fig. 5i), Si and O elements are homogenously distributed in the C element, suggesting that Si NPs are uniformly spread in the carbon matrix consist of rGO and amorphous carbon.

To investigate the enhanced electronic conductivity of these composites induced by the introduction of carbon materials, powder electronic conductivity of pristine Si, Si-rGO, Si-C and Si-rGO-C samples were measured at the pressure of 2 MPa. As shown in Table 1, the hybridization with both amorphous carbon and graphene can effectively increase the electronic conductivity of Si-based materials. And the Si-rGO-C composite possesses the highest electronic conductivity. Thus constructing synergistic carbon coating layers is very important in the Si-rGO-C composite. The carbon coating layer can enhance the electronic conductivity of Si NPs and help to form stable solid electrolyte interface (SEI) on the surface. The highly conductive and flexible rGO can further facilitate electrons transport through the whole electrode and accommodate huge volume changes during cycling. The Si-rGO-C composite is expected to possess superior electrochemical performance benefit by the synergistic carbon coating layers in the composite structure.

Table 1

<table>
<thead>
<tr>
<th>Samples</th>
<th>Conductivity (S cm⁻¹)</th>
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<tbody>
<tr>
<td>Pristine Si</td>
<td>7.58 × 10⁻⁶</td>
</tr>
<tr>
<td>Si-rGO composite</td>
<td>1.18</td>
</tr>
<tr>
<td>Si-C composite</td>
<td>0.059</td>
</tr>
<tr>
<td>Si-rGO-C composite</td>
<td>2.91</td>
</tr>
</tbody>
</table>
cathodic process, two broad peaks at around 1.37 and 1.12 V can be attributed to the side reactions of Li\(^{+}\) ions with the residual oxygen-containing groups in rGO and the formation of solid electrolyte layer (SEI), which disappear in the following cycles [33, 45]. The two weak anodic peaks at 0.15 – 0.2 V may be due to the reaction of Li\(^{+}\) with carbon materials (rGO and amorphous carbon) [46–48]. The cathodic peak at –0.19 V and the anodic peaks at –0.33 and –0.50 V are characteristic peaks of amorphous Si, and the cathodic peak at nearly 0 V is coincidental for both crystalline and amorphous Si [47, 49]. Because Si in the Si-rGO-C composite is crystalline, only one peak at –0 V is observed in the first cathodic process. An addition cathodic peak at –0.19 V appears in the cathodic processes, and two anodic peaks at –0.33 and –0.50 V which are related to the dealloy steps of Li\(_x\)Si become broader and stronger as a result of cycling [50, 51]. This phenomenon is a common feature to the conversion of crystalline Si into amorphous Si during the repeated lithiation and delithiation [16, 52, 53].

The electrochemical performances of Si-rGO, Si-C and Si-rGO-C composites are evaluated by the galvanostatic method. The cyclic performances of these samples at 0.5 A g\(^{-1}\) are shown in Fig. 7a. These electrodes were activated at 0.1 A g\(^{-1}\) for the first 5 cycles and then cycled at the higher current densities for all the subsequent cycles. Obviously, the Si-rGO-C composite exhibits the best cyclic stability. The first charge capacity of the Si-rGO-C composite at 0.5 A g\(^{-1}\) (the...
6th cycle) is 913 mAh g⁻¹. And the high capacity of 910 mAh g⁻¹ is still retained after 100 cycles, which indicates a negligible capacity decay. The charge-discharge voltage profiles of the Si-rGO-C composite (Fig. 7b) overlap well during cycling, which reflects the high cyclic stability and small polarization degree of the electrode. The Si-rGO and Si-C composites show higher initial charge capacities (1829 and 1348 mAh g⁻¹, respectively) at 0.5 A g⁻¹, due to the higher content of Si in the composites. However, the capacities fade quickly after 100 cycles corresponding to the charge capacity retention of 13% and 30%, respectively. At a higher current density of 1 A g⁻¹, the Si-rGO-C composite shows a charge capacity of 805 mAh g⁻¹, with a charge capacity retention of 98.3%. However, the Si-rGO and Si-C composites only exhibit charge capacities of 291 and 354 mAh g⁻¹ with charge capacity retentions of 18% and 29%, respectively.

Rate capability of the Si-rGO-C composite was also investigated (Fig. 7d and e). The cells were cycled at various current densities ranging from 0.1 A g⁻¹ to 5 A g⁻¹. The Si-rGO-C composite exhibits an average capacity of 1060 mAh g⁻¹ at the low current density of 0.1 A g⁻¹. The reversible capacities of 1029, 940, 795 and 632 mAh g⁻¹ can be achieved at the high current densities of 0.2, 0.5, 1 and 2 A g⁻¹, respectively. Even at a very high current density of 5 A g⁻¹ (every cycle finished at about 10 min), a high reversible capacity of 428 mAh g⁻¹ is maintained which is still higher than the theoretical capacity of graphite. Besides, after the current density returns to 0.1 A g⁻¹, the charge capacity quickly recovers to 1059 mAh g⁻¹, which demonstrates the good reversibility. The long-term cyclic performance is another important character to LIB anodes. The Si-rGO-C composite exhibits the charge capacity of 593 mAh g⁻¹ with the capacity retention of 88% after 200 cycles at the high current density of 2 A g⁻¹ (Fig. 7f), demonstrating the outstanding long-term cyclic stability during high rate cycling.

To further study the origin of the superior electrochemical performance, EIS measurements of all the composites were performed after the initial cycle at the fully delithiated state. Every EIS plot consists of a compressed semicircle in the high to medium frequency region and a straight line in the low frequency region (Fig. 8). The semicircle is attributed to the charge-transfer resistance (Rct, might contain the SEI region (Fig. 8). The semicircle is attributed to the charge-transfer resistance (Rct, might contain the SEI region), and the straight line is related to the diffusion of Li⁺ ions into the anode material [54,55]. The EIS data are fitted by using the equivalent circuit (inset in Fig. 8), and more details are shown in Table 2. These results clearly reveal that the Si-rGO-C composite electrode presents the smallest Rct, among all the three samples, which is favorable for rapid charge and discharge.

Among the three composites studied, the Si-rGO-C composite possesses the best electrochemical performance. The superior cyclic stability can be attributed to the successful construction of the synergistic protective layers (amorphous carbon and rGO). The Si-rGO and Si-C composites with a singular protective layer cannot ensure the structural integrity and electronic conductivity in the whole electrode.

4. Conclusions

The Si-rGO-C ternary composite with synergistic protective layers of both amorphous carbon and rGO has been successfully synthesized by a facile guar gel hydrogel method. The amorphous carbon and rGO serve as synergistic protective layers. The amorphous carbon coating layer embedded with Si NPs can enhance electronic conductivity and help to form the stable SEI layers on the surface. The rGO coating layers not only form a conductive network in the whole material but also can buffer the mechanical stress induced by volume change of Si during cycling. Thus the excellent structural stability and conductive network offer the Si-rGO-C ternary composite superior electrochemical performance, compared with the Si-rGO and Si-C composites with a singular protective layer. Besides, all the raw materials are commercial products and the synthesis route is simple and scalable. The Si-rGO-C ternary composite can be a promising high capacity anode for LIBs.

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